To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

Send any inquiries to http://www.renesas.com/inquiry.

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(Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

RENESAS

SILICON TRANSISTOR

2SD992-Z

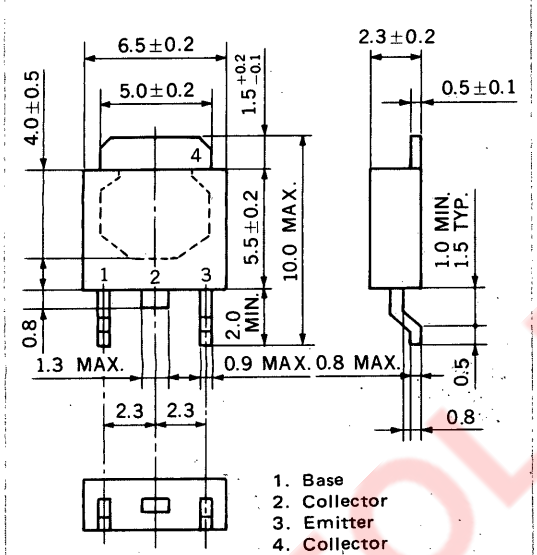
NPN SILICON EPITAXIAL TRANSISTOR

MP-3

DESCRIPTION

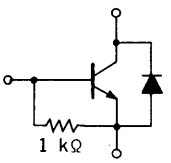
2SD992-Z is designed for Audio Frequency Amplifier and Switching, especially in Hybrid Integrated Circuits.

PACKAGE DIMENSIONS
in millimeters



FEATURES

- Low $V_{CE(sat)}$: $V_{CE(sat)}$ = 0.3 V TYP.
- B-E Resistor, Built-in
- Complement to 2SB962-Z



ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Currents (T_a = 25 °C)

Collector to Base Voltage	V_{CBO}	30	V
Collector to Emitter Voltage	V_{CEO}	30	V
Emitter to Base Voltage	V_{EBO}	5	V
Collector Current (DC)	I_C	2	A
Collector Current (Pulse)*	I_C	3	A
Maximum Power Dissipation			
Total Power Dissipation at 25 °C Ambient Temperature**	P_T	2.0	W
Maximum Temperatures			
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	−55 to +150	°C

*PW ≦ 10 ms, Duty Cycle ≦ 50 %

**When mounted on ceramic substrate of 2.5 cm². x 0.7 mm

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			10	μA	V_{CB} = 20 V, I_E = 0
DC Current Gain	h_{FE1}***	35		200		V_{CE} = 0.5 V, I_C = 0.1 A
DC Current Gain	h_{FE2}***	50				V_{CE} = 0.5 V, I_C = 2.0 A
Collector Saturation Voltage	$V_{CE(sat)}$***		0.3	0.5	V	I_C = 2.0 A, I_B = 40 mA
Base Saturation Voltage	$V_{BE(sat)}$***		0.95	1.5	V	I_C = 2.0 A, I_B = 40 mA

***Pulsed: PW ≦ 350 μs, Duty Cycle ≦ 2 %

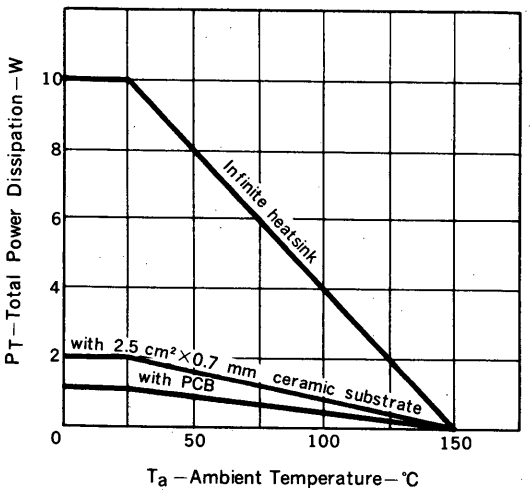
h_{FE} Classification

MARKING	N	M	L	K
h_{FE1}	35 to 80	60 to 120	80 to 120	100 to 200

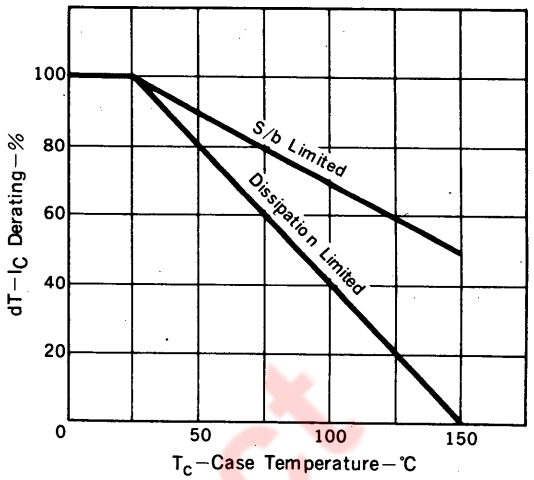
NEC Corporation

TYPICAL CHARACTERISTICS (T_a = 25 °C)

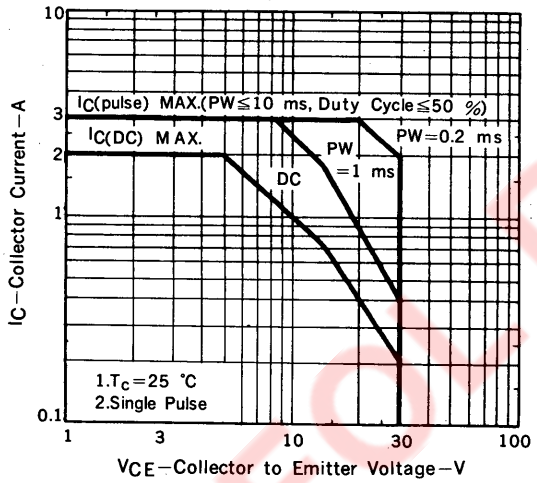
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



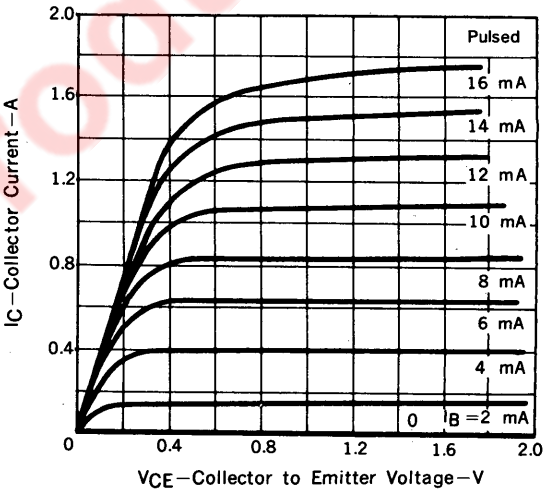
DERATING CURVE OF SAFE OPERATING AREAS



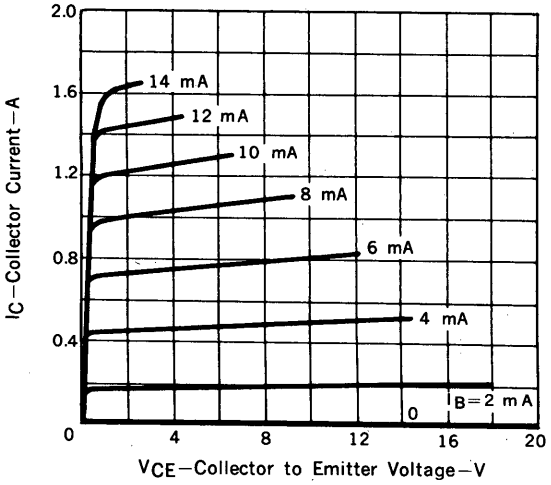
SAFE OPERATING AREAS



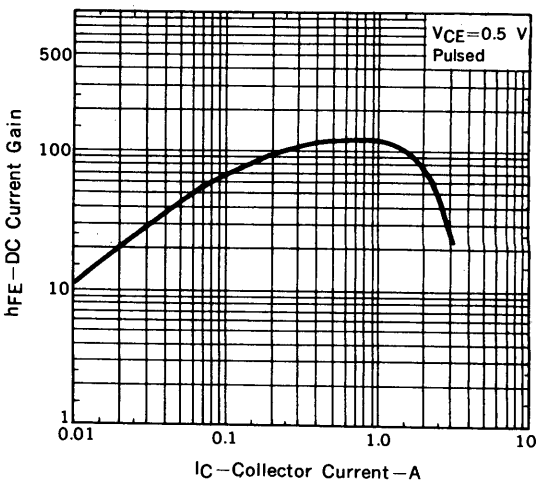
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



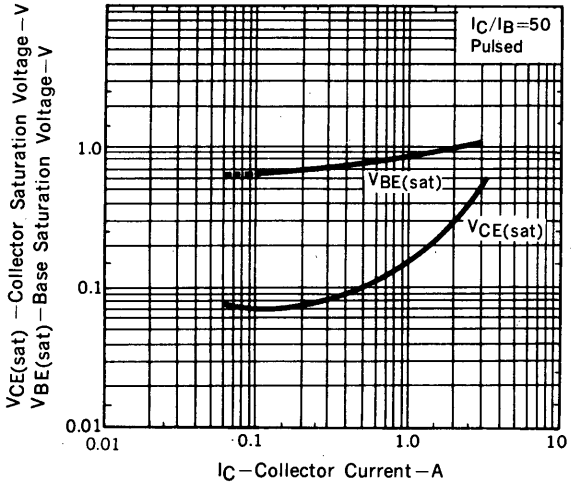
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



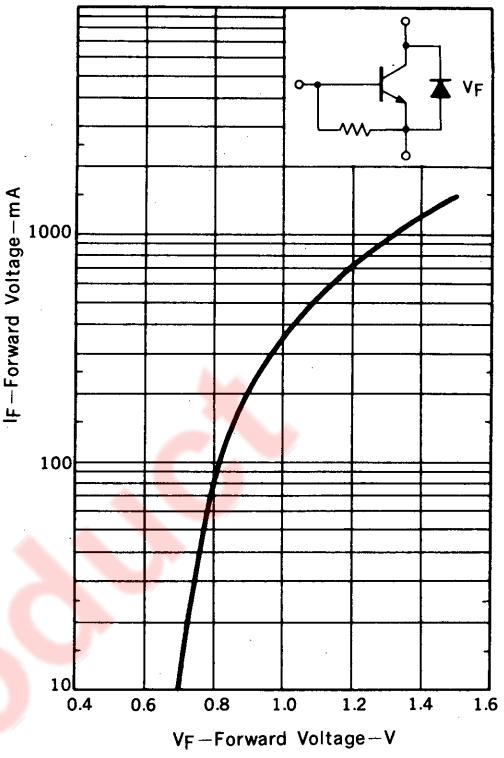
DC CURRENT GAIN vs. COLLECTOR CURRENT



BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



FORWARD CURRENT vs. FORWARD VOLTAGE



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